		•			-	
A ACDC_TOPSwitchJX_011911; Rev.1.4;	В	С	D	Е	TOP IV 011011: TOPSwitch IV Continuous/Discontinuous	
Copyright Power Integrations 2010	INPUT	INFO	OUTPUT	LINIT	TOP_JX_011911: TOPSwitch-JX Continuous/Discontinuous Flyback Transformer Design Spreadsheet	
ENTER APPLICATION VARIABLES	INFOT	III O	001101	CIVIT	Design title	
VACMIN	195			Volts	Minimum AC Input Voltage	
VACMAX	265			Volts	Maximum AC Input Voltage	
fL	50			Hertz	AC Mains Frequency	
vo	24.00			Volts	Output Voltage (main)	
PO_AVG	26.00			Watts	Average Output Power	
PO_PEAK	26.00		26.00	Watts	Peak Output Power	
Heatsink Type	PCB		PCB		Heatsink Type	
Factories	Adapter				Open Frame enclosure assume sufficienct airflow while adapter means a	
Enclosure	0.85			%/100	sealed enclosure.  Efficiency Estimate	
7	0.50			707 100	Loss allocation factor	
VB	15			Volts	Bias Voltage - Verify that VB is > 8 V at no load and VMAX	
tC	3.00			ms	Bridge Rectifier Conduction Time Estimate	
CIN	33.0		33	uFarads	Input Filter Capacitor	
ENTER TOPSWITCH-JX VARIABLES						
TOPSwitch-JX	TOP266K			Universal / Peak	115 Doubled/230V	
Chosen Device		TOP266K	Power Out	36 W / 58 W	36W	
171	0.00				External Ilimit reduction factor (KI=1.0 for default ILIMIT, KI <1.0 for lower	
KI ILIMITMIN EXT	0.29		0.688	Amps	Use 1% resistor in setting external ILIMIT	
ILIMITMIN_EXT			0.791	Amps	Use 1% resistor in setting external ILIMIT	
Frequency (F)=132kHz, (H)=66kHz	Н		H		Select 'H' for Half frequency - 66kHz, or 'F' for Full frequency - 132kHz	
fs	<del></del>		66000	Hertz	TOPSwitch-JX Switching Frequency: Choose between 132 kHz and 66 kHz	
fSmin			59400	Hertz	TOPSwitch-JX Minimum Switching Frequency	
fSmax			72600	Hertz	TOPSwitch-JX Maximum Switching Frequency	
High Line Operating Mode			FF		Full Frequency, Jitter enabled	
VOR	100.00			Volts	Reflected Output Voltage	
VDS			10	Volts	TOPSwitch on-state Drain to Source Voltage	
VD VDB	0.50			Volts	Output Winding Diode Forward Voltage Drop	
VDB KP	0.70 0.60			Volts	Bias Winding Diode Forward Voltage Drop  Ripple to Peak Current Ratio (0.3 < KRP < 1.0 : 1.0 < KDP < 6.0)	
INP	0.60				Ripple to Peak Current Ratio (0.3 < KRP < 1.0 : 1.0 < KDP < 6.0)	
PROTECTION FEATURES						
LINE SENSING					V pin functionality	
VUV_STARTUP			218	Volts	Minimum DC Bus Voltage at which the power supply will start-up	
VOV_SHUTDOWN			1050	Volts	Typical DC Bus Voltage at which power supply will shut-down (Max)	
					Use two standard, 4.7 M-Ohm, 5% resistors in series for line sense	
RLS			9.4	M-ohms	functionality.	
OUTPUT OVERVOLTAGE			07	No. He	Zero Brotz and allow 6 Garage	
VZ RZ			5.1	Volts	Zener Diode rated voltage for Output Overvoltage shutdown protection  Output OVP resistor. For latching shutdown use 20 ohm resistor instead	
OVERLOAD POWER LIMITING			J. I	k-ohms	X pin functionality	
OTENEDAD I OTTEN LIMITING						
					Enter the desired margin to current limit at VMAX. A value of 1.2 indicates that the current limit should be 20% higher than peak primary current at	
Overload Current Ratio at VMAX			1.2		VMAX	
Overload Current Ratio at VMIN			1.17		Margin to current limit at low line.	
ILIMIT_EXT_VMIN			0.59	A	Peak primary Current at VMIN	
ILIMIT_EXT_VMAX			0.57	A	Peak Primary Current at VMAX	
RIL			18.30	k-ohms	Current limit/Power Limiting resistor.	
RPL			N/A	M-ohms	Resistor not required. Use RIL resistor only	
ENTER TRANSFORMER CORE/CONSTRUCTIO	N VADIARI ES					
Core Type	Auto		EF25		Core Type	
Core	Auto	EF25		P/N:	PC40EF25-Z	
Bobbin		EF25_BOBBIN		P/N:	*	
AE	·		0.518	cm^2	Core Effective Cross Sectional Area	
LE			5.78	cm	Core Effective Path Length	
AL			2000	nH/T^2	Ungapped Core Effective Inductance	
BW			15.6	mm	Bobbin Physical Winding Width	
M	0.00			mm	Safety Margin Width (Half the Primary to Secondary Creepage Distance)	
L NC	3.00		26		Number of Primary Layers	
NS			36		Number of Secondary Turns	
DC INPUT VOLTAGE PARAMETERS						
VMIN			251	Volts	Minimum DC Input Voltage	
VMAX			375	Volts	Minimum DC Input Voltage  Maximum DC Input Voltage	
			37.0	- 0110	massina in DO input voltage	
CURRENT WAVEFORM SHAPE PARAMETERS						
DMAX			0.29		Maximum Duty Cycle (calculated at PO_PEAK)	
IAVG			0.12	Amps	Average Primary Current (calculated at average output power)	
IP			0.59	Amps	Peak Primary Current (calculated at Peak output power)	
IR			0.36	Amps	Primary Ripple Current (calculated at average output power)	
IRMS			0.23	Amps	Primary RMS Current (calculated at average output power)	
TRANSFORMED DRIMARY DESIGN DARASET	EDC					
TRANSFORMER PRIMARY DESIGN PARAMET	EKO		2577	ulloprice	Primary Industrance	
LP LP Tolerance			3577 10	uHenries	Primary Inductance Tolerance of Primary Inductance	
NP			147		Primary Winding Number of Turns	
NB			23		Bias Winding Number of Turns  Bias Winding Number of Turns	
ALG			166	nH/T^2	Gapped Core Effective Inductance	
BM			2789	Gauss	Maximum Flux Density at PO, VMIN (BM<3000)	
					Peak Flux Density (BP<4200) at ILIMITMAX and LP_MAX. Note:	
				_	Recommended values for adapters and external power supplies <=3600	
BP PAC			4089	Gauss	Gauss	
BAC			837	Gauss	AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)	

A	В	С	D	E	F	
ur			1776		Relative Permeability of Ungapped Core	
LG			0.36	mm	Gap Length (Lg > 0.1 mm)	
BWE			46.8	mm	Effective Bobbin Width	
OD			0.32	mm	Maximum Primary Wire Diameter including insulation	
INS			0.05	mm	Estimated Total Insulation Thickness (= 2 * film thickness)	
DIA			0.26	mm	Bare conductor diameter	
AWG			30	AWG	Primary Wire Gauge (Rounded to next smaller standard AWG value)	
CM			102	Cmils	Bare conductor effective area in circular mils	
CMA			438	Cmils/Amp	Primary Winding Current Capacity (200 < CMA < 500)	
Primary Current Density (J)			4.57	Amps/mm^2	Primary Winding Current density (3.8 < J < 9.75)	
Timal y canonic point, (c)				7 411	riman, rimang sunon asim, (see 15 15)	
TRANSFORMER SECONDARY DESIGN PARAM	METERS (SINGLE	OUTPUT EC	UIVALEN	Γ)		
Lumped parameters						
ISP			2.42	Amps	Peak Secondary Current	
SRMS			1.47	Amps	Secondary RMS Current	
O_PEAK			1.08	Amps	Secondary Peak Output Current	
0			1.08	Amps	Average Power Supply Output Current	
IRIPPLE			0.99	Amps	Output Capacitor RMS Ripple Current	
CMS AWGS			294 25	Cmils	Secondary Mire Gauge (Pounded up to payt larger standard AMG value)	
AWGS				<u> </u>	Secondary Wire Gauge (Rounded up to next larger standard AWG value)	
DIAS			0.46	mm	Secondary Minimum Bare Conductor Diameter	
ODS			0.43	mm	Secondary Maximum Outside Diameter for Triple Insulated Wire	
INSS			-0.01	mm	Maximum Secondary Insulation Wall Thickness	
VOLTAGE STRESS PARAMETERS						
VDRAIN			575	Volts	Maximum Drain Voltage Estimate (Includes Effect of Leakage Inductance)	
PIVS			116	Volts	Output Rectifier Maximum Peak Inverse Voltage	
PIVB			74	Volts	Bias Rectifier Maximum Peak Inverse Voltage	
TRANSCORMER OF COURT BY BESIEVE TO THE	1ETEDO (141 11 T'	E OUEDUE	2)			
TRANSFORMER SECONDARY DESIGN PARAM	IETEKS (MULTIPL	E OUTPUTS	<b>&gt;</b> )			
1st output						
VO1	24.00		24	Volts	Output Voltage	
IO1_AVG	1.10		1.10	Amps	Average DC Output Current	
PO1_AVG			26.40	Watts	Average Output Power	
VD1			0.5	Volts	Output Diode Forward Voltage Drop	
NS1			36.00		Output Winding Number of Turns	
ISRMS1			1.491	Amps	Output Winding RMS Current	
IRIPPLE1			1.01	Amps	Output Capacitor RMS Ripple Current	
PIVS1			116	Volts	Output Rectifier Maximum Peak Inverse Voltage	
			298		-	
CMS1				Cmils	Output Winding Bare Conductor minimum circular mils	
AWGS1			25	AWG	Wire Gauge (Rounded up to next larger standard AWG value)	
DIAS1			0.46	mm	Minimum Bare Conductor Diameter	
ODS1			0.43	mm	Maximum Outside Diameter for Triple Insulated Wire	
2nd output						
VO2				Volts	Output Voltage	
IO2_AVG				Amps	Average DC Output Current	
PO2 AVG			0.00	Watts	Average Output Power	
VD2			0.7	Volts	Output Diode Forward Voltage Drop	
NS2			1.03		Output Winding Number of Turns	
ISRMS2			0.000	Amps	Output Winding RMS Current	
IRIPPLE2			0.000	Amps	Output Capacitor RMS Ripple Current	
			3	Volts		
PIVS2					Output Rectifier Maximum Peak Inverse Voltage	
CMS2			0	Cmils	Output Winding Bare Conductor minimum circular mils	
AWGS2			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)	
DIAS2			N/A	mm	Minimum Bare Conductor Diameter	
ODS2			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire	
3rd output						
VO3	<u> </u>			Volts	Output Voltage	
IO3_AVG				Amps	Average DC Output Current	
PO3_AVG			0.00	Watts	Average Output Power	
VD3			0.7	Volts	Output Diode Forward Voltage Drop	
NS3			1.03		Output Winding Number of Turns	
ISRMS3			0.000	Amps	Output Winding RMS Current	
IRIPPLE3			0.00	Amps	Output Capacitor RMS Ripple Current	
PIVS3			3	Volts	Output Rectifier Maximum Peak Inverse Voltage	
CMS3			0	Cmils	Output Winding Bare Conductor minimum circular mils	
AWGS3			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)	
DIAS3			N/A	mm	Minimum Bare Conductor Diameter	
ODS3			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire	
Total Continuous Output Power			26.4	Watts	Total Continuous Output Power	
					If negative output exists enter Output number; eg: If VO2 is negative output,	
Negative Output			N/A		enter 2	

## **Transformer Construction Parameters**

Var	Value	Units	Description
Core Type	EF25		Core Type
Core Material	NC-2H (Nicera) or Equivalent		Core Material
Bobbin Reference	Generic, 5 pri. + 5 sec.		Bobbin Reference
Bobbin Orientation	Horizontal		Bobbin type
Primary Pins	5		Number of Primary pins used
Secondary Pins	5		Number of Secondary pins used
LP	3219	μΗ	Primary Inductance
ML	0.00	mm	Safety Margin on Left Width
MR	0.00	mm	Safety Margin on Right Width
LG	0.360	mm	Estimated Gap Length

## **Bias Variables**

Var	Value	Units	Description
NB	24		Bias Winding Number of Turns
Wire Size	30	AWG	Wire size of Bias windings
Winding Type	Bifilar (x2)		Wire type of Bias windings
Layers	0.91		Bias Winding Layers
Start Pin(s)	1		Starting pin(s) for Bias winding (Manual Input)
Termination Pin(s)	2		Termination pin(s) for Bias winding (Manual Input)

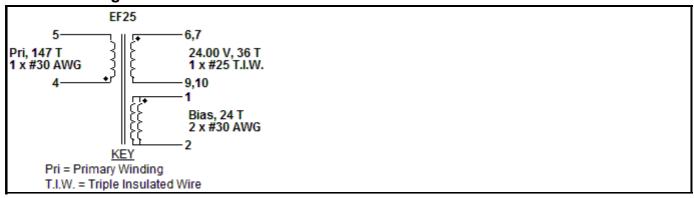
# **Primary Winding Section 1**

Var	Value	Units	Description
NP1	147		Rounded (Integer) Number of Primary winding turns in the first section of primary
Wire Size	30	AWG	Wire size of primary winding
Winding Type	Single (x1)		Primary winding number of parallel wire strands
L	2.78		Primary Number of Layers
Start Pin(s)	4		Starting pin(s) for first section of primary winding (Manual Input)
Termination Pin(s)	5		Termination pin(s) for first section of primary winding (Manual Input)

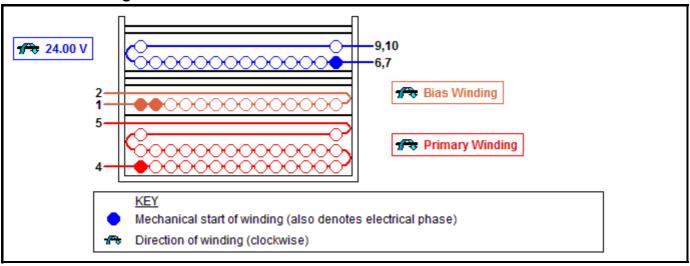
# Output 1

Var	Value	Units	Description
VO	24.00	V	Output Voltage
Ю	1.10	Α	Output Current
VOUT_ACTUAL	24.00	V	Actual Output Voltage
NS	36		Secondary Number of Turns
Wire Size	25	AWG	Wire size of secondary winding
Winding Type	Single (x1)		Output winding number of parallel strands
L_S_OUT	1.50		Secondary Output Winding Layers
Start Pin(s)	6,7		Starting pin(s) for Output winding (Manual Input)
Termination Pin(s)	9,10		Termination pin(s) for Output winding (Manual Input)

### **Electrical Diagram**



### **Mechanical Diagram**



## Winding Instruction

## **Primary Winding**

Start on pin(s) 4 and wind 147 turns (x 1 filar) of item [5] in 3 layer(s) from left to right. At the end of 1st layer, continue to wind the next layer from right to left. At the end of 2nd layer, continue to wind the next layer from left to right. On the final layer, spread the winding evenly across entire bobbin. Finish this winding on pin(s) 5.

Add 1 layer of tape, item [3], for insulation.

#### **Bias Winding**

Start on pin(s) 1 and wind 24 turns (x 2 filar) of item [5]. Wind in same rotational direction as primary winding. Spread the winding evenly across entire bobbin. Finish this winding on pin(s) 2.

Add 3 layers of tape, item [3], for insulation.

#### **Secondary Winding**

Start on pin(s) 6,7 and wind 36 turns (x 1 filar) of item [6]. Spread the winding evenly across entire bobbin. Wind in same rotational direction as primary winding. Finish this winding on pin(s) 9,10.

Add 2 layers of tape, item [3], for insulation.

#### **Core Assembly**

Assemble and secure core halves. Item [1].

#### Varnish

Dip varnish uniformly in item [4]. Do not vacuum impregnate

#### **Comments**

- 1. Pins 6 and 7 are electrically shorted to each other on the PCB via a copper trace.
- 2. Pins 9 and 10 are electrically shorted to each other on the PCB via a copper trace.
- 3. For non margin wound transformers use triple insulated wire for all secondary windings.

#### **Materials**

Item	Description
[1]	Core: EF25, NC-2H (Nicera) or Equivalent, gapped for ALG of 166 nH/t <sup>2</sup>
[2]	Bobbin: Generic, 5 pri. + 5 sec.
[3]	Barrier Tape: Polyester film [1 mil (25 µm) base thickness], 15.60 mm wide
[4]	Varnish
[5]	Magnet Wire: 30 AWG, Solderable Double Coated
[6]	Triple Insulated Wire: 25 AWG

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## **Electrical Test Specifications**

Parameter	Condition	Spec
Electrical Strength, VAC	60 Hz 1 second, from pins 1,2,4,5 to pins 6,7,9,10.	3000
Nominal Primary Inductance, µH	Measured at 1 V pk-pk, typical switching frequency, between pin 4 to pin 5, with all other Windings open.	3577
Tolerance, ±%	Tolerance of Primary Inductance	10.0
Maximum Primary Leakage, μΗ	Measured between Pin 4 to Pin 5, with all other Windings shorted.	107.3

Although the design of the software considered safety guidelines, it is the user's responsibility to ensure that the user's power supply design meets all applicable safety requirements of user's product.

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.

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